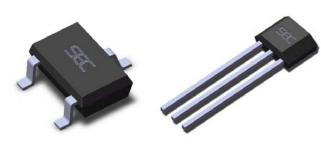


#### Packages



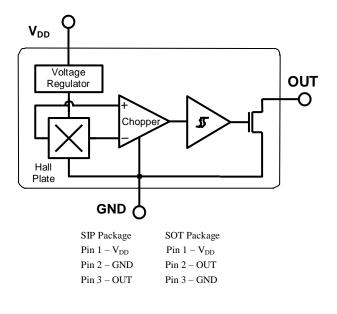
3 pin SOT23 (suffix SO)

3 pin SIP (suffix UA)

#### **Features and Benefits**

- 3.5V to 24V Operation
- -40°C to 150°C Superior temperature operation
- CMOS technology
- Low current consumption
- Chopper-stabilized amplifier stage
- Open drain output
- Low sensitivity
- Small Size SOT23 3L or SIP 3L Both RoHS compliant packages

#### **Functional Block Diagram**



### **Application Examples**

- Automotive, Consumer and Industrial
- Solid-state switch
- Brushless DC motor commutation
- Speed detection
- Angular position detection
- Proximity detection
- Current detector

#### **General Description**

The SS159 is a unipolar Hall-effect sensor IC fabricated from CMOS technology. The device integrates a voltage regulator, Hall sensor with dynamic offset cancellation system, small signal amplifier, Schmitt trigger and an open-drain output driver. With suitable output pull up, they can be used with bipolar or CMOS logic circuits.

These Hall-effect switches are monolithic integrated circuits with tighter magnetic specifications, designed to operate continuously over extended temperatures to +150°C, and are more stable with both temperature and supply voltage changes. The unipolar switching characteristic makes these devices ideal for use with a simple bar or rod magnet.

Thanks to its wide operating voltage range and extended choice of temperature range, it is quite suitable for use in automotive, industrial and consumer applications.

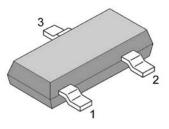
The device is delivered in a Small Outline Transistor (SOT) and in a Plastic Single In Line (SIP 3L flat). Both 3-lead packages are RoHS compliant.

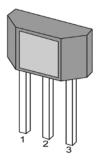


## **Glossary of Terms**

MilliTesla (mT), Gauss	Units of magnetic flux density: $1mT = 10$ Gauss
RoHS	Restriction of Hazardous Substances
Operating Doint (P)	Magnetic flux density applied on the branded side of the package which turns the
Operating Point $(B_{OP})$	output
	driver ON ( $V_{OUT} = V_{DSon}$ )
Release Point (B <sub>RP</sub> )	Magnetic flux density applied on the branded side of the package which turns the
Release I offit (DRP)	output
	driver OFF ( $V_{OUT} = high$ )

## **Pin Definitions and Descriptions**





SOT Pin №	SIP Pin №	Name	Туре	Function
1	1	V <sub>DD</sub>	Supply	Supply Voltage pin
2	3	OUT	Output	Open Drain Output pin
3	2	GND	Ground	Ground pin

#### **Absolute Maximum Ratings**

Parameter	Symbol	Value	Units
Supply Voltage	V <sub>DD</sub>	28	V
Supply Current	I <sub>DD</sub>	50	mA
Output Voltage	V <sub>OUT</sub>	28	V
Output Current	I <sub>OUT</sub>	50	mA
Storage Temperature Range	T <sub>S</sub>	-65 to 170	°C

<b>Operating Temperature Range</b>	Symbol	Value	Units
Temperature Suffix "E"	T <sub>A</sub>	-40 to 85	°C
Temperature Suffix "K"	T <sub>A</sub>	-40 to 125	°C
Temperature Suffix "L"	T <sub>A</sub>	-40 to 150	°C

Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



## **General Electrical Specifications**

DC Operating Parameters  $T_A = 25^{\circ}$ C,  $V_{DD} = 3.5$ V to 24V (unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Supply Voltage	V <sub>DD</sub>	Operating	3.5		24	V
Supply Current	I <sub>DD</sub>	$B < B_{RP}$	1.5	2.5	5	mA
Output Saturation Voltage	V <sub>DSon</sub>	$I_{OUT} = 20 \text{mA}, \text{ B} > B_{OP}$		0.4	0.5	V
Output Leakage Current	I <sub>OFF</sub>	$B < B_{RP} V_{OUT} = 24 V$		0.01	10	μA
Output Rise Time	t <sub>r</sub>	$R_L = 1k\Omega, C_L = 20pF$		0.25		μs
Output Fall Time	t <sub>f</sub>	$R_L = 1k\Omega, C_L = 20pF$		0.25		μs

## **Magnetic Specifications**

DC Operating Parameters  $V_{DD} = 3.5V$  to 24V (unless otherwise specified)

Package	Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
	Operating Point	B <sub>OP</sub>		100	125	150	G
UA	Release Point	B <sub>RP</sub>	Ta=25°C,Vdd=12V DC	60	85	110	G
	Hysteresis	B <sub>HYST</sub>			40		G
	Operating Point	B <sub>OP</sub>	Ta=25°C,Vdd=12V DC	-150	-125	-100	G
SO	Release Point	B <sub>RP</sub>		-110	-85	-60	G
	Hysteresis	B <sub>HYST</sub>			40		G

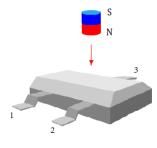
## **Output Behavior versus Magnetic Pole**

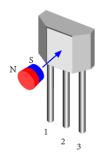
DC Operating Parameters  $T_A = -40^{\circ}$ C to 150°C,  $V_{DD} = 3.5$ V to 24V (unless otherwise specified)

Test Conditions (UA)	Test Conditions (SO)	OUT	
$B < B_{RP}$	$B > B_{RP}$	High	
$B > B_{OP}$	$B < B_{OP}$	Low	

The SOT-23 device is reversed from the UA package. The SOT-23 output transistor will be turned on(drops low) in the

presence of a sufficiently strong North pole magnetic field applied to the marked face.

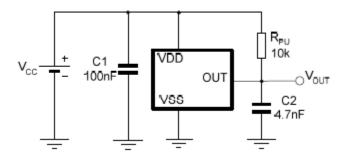




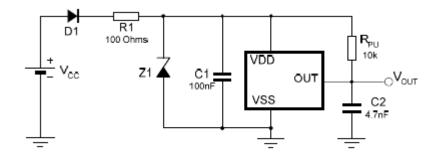


#### **Application Information**

**Typical Three-Wire Application Circuit** 



Automotive and Harsh, Noisy Environments Three-Wire Circuit



## **Application Comments**

For proper operation, a 100nF bypass capacitor should be placed as close as possible to the device between the  $V_{DD}$  and ground pin.

For reverse voltage protection, it is recommended to connect a resistor or a diode in series with the V<sub>DD</sub> pin.

When using a resistor, three points are important:

- the resistor has to limit the reverse current to 50mA maximum (V\_{CC} / R1  $\leq$  50mA)
- the resulting device supply voltage  $V_{DD}$  has to be higher than  $V_{DD}$  min ( $V_{DD} = V_{CC} R1.I_{DD}$ )
- the resistor has to withstand the power dissipated in reverse voltage condition ( $P_D = V_{CC}^2/R1$ )

When using a diode, a reverse current cannot flow and the voltage drop is almost constant ( $\approx 0.7$ V).

Therefore, a 100  $\Omega$  /0.25W resistor for 5V application and a diode for higher supply voltage are recommended.

When a weak power supply is used or when the device is intended to be used in noisy environment, it is recommended the second figure above is used.

The low-pass filter formed by R1 and C1 and the Zener diode Z1 bypass the disturbances or voltage spikes occurring on the device supply voltage  $V_{DD}$ . The diode D1 provides additional reverse voltage protection.

Both solutions provide the required reverse voltage protection.



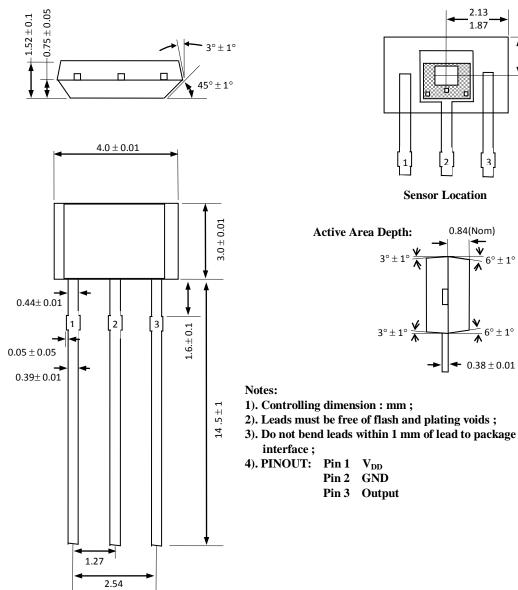
1.00 1.20

### **ESD** Precautions

Electronic semiconductor products are sensitive to Electro Static Discharge (ESD). Always observe Electro Static Discharge control procedures whenever handling semiconductor products.

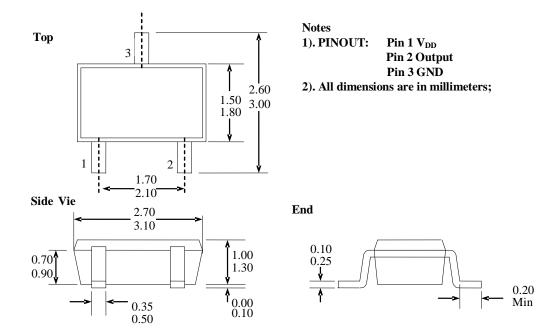
## **Package Information**

#### Package UA, 3-Pin SIP:





#### Package SO, 3-Pin SOT-23:



# **Ordering Information**

Part No.	Pb-free	Temperature Code	Package Code	Packing
SS159ESOT	YES	-40°C to 85°C	SOT-23	7-in. reel, 3000 pieces/reel
SS159EUA	YES	-40°C to 85°C	TO-92	Bulk, 1000 pieces/bag
SS159KSOT	YES	-40°C to 125°C	SOT-23	7-in. reel, 3000 pieces/reel
SS159KUA	YES	-40°C to 125°C	TO-92	Bulk, 1000 pieces/bag
SS159LSOT	YES	-40°C to 150°C	SOT-23	7-in. reel, 3000 pieces/reel
SS159LUA	YES	-40°C to 150°C	TO-92	Bulk, 1000 pieces/bag